

# PHOTOMULTIPLIER TUBE R13096

## **FEATURES**

●2 × wider sensitive area while maintaing equivalent QE (and gain) at conventional PMTs.

## **APPLICATIONS**

- Spectroscopy
- Environmental monitoring
- Chemiluminescence measurement
- Biomedical analysis

Figure 1: Uniformity Area

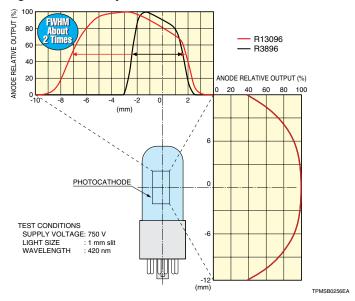
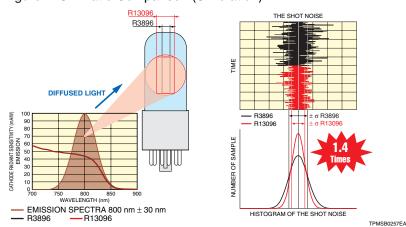


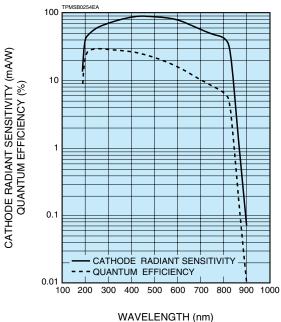
Figure 2: SN Ratio Comparison (Simulation)





Left: R13096, Right: R3896

Figure 3: Typical Spectral Response



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## PHOTOMULTIPLIER TUBE R13096

## SPECIFICATIONS

### **GENERAL**

Pa	rameter	Description/Value	Unit
Spectral Respo	onse	185 to 900	nm
Wavelength of	Maximum Response	450	nm
Photocathode	Material	Multialkali	_
Filolocalilode	Minimum Effective Area	10 × 24	mm
Window Mater	al	UV glass	_
Dynode	Structure	Circular-cage	_
	Number of Stages	9	_
Direct	Anode to Last Dynode	4	pF
Interelectrode	Anode to All Other	6	nE
Capacitances	Electrodes	0	pF
Base		11-pin base JEDEC No. B11-88	_
Weight		Approx. 45	g
Operating Amb	ient Temperature	-30 to +50	°C
Storage Tempe	erature	-30 to +50	°C
Suitable Socke	et	E678-11A (Sold Separately)	_
Suitable Socke	t Assembly	E717-63 (Sold Separately)	

### **MAXIMUM RATINGS (Absolute Maximum Values)**

	Parameter	Value	Unit
Supply	Between Anode and Cathode	1250	V
Voltage	Between Anode and Last Dynode	250	V
Average	Anode Current <sup>A</sup>	0.1	mA

### CHARACTERISTICS (at 25 °C)

	Para	meter		Min.	Тур.	Max.	Unit	
			at 194 nm	_	21	_	%	
	Oua	ntum	at 254 nm	_	29		%	
		iency	at 450 nm	_	25	_	%	
	LIIIC	Лепсу	at 633 nm	_	14	_	%	
			at 852 nm	_	0.73	_	%	
Cathode	Lum	inous <sup>B</sup>		475	525	_	μ <b>A</b> /lm	
Sensitivity			at 194 nm		33	_	mA/W	
Sensitivity			at 254 nm		60	_	mA/W	
	Rad	iant	at 450 nm	_	90	_	mA/W mA/W	
			at 633 nm	_	73	_		
			at 852 nm	_	5.0	_	mA/W	
	Red	/White	Ratio <sup>C</sup>	_	0.4	_	_	
	Blue	Sensit	ivity Index D	_	15	_	_	
Anode Sensitivity	Lum	inous <sup>E</sup>		3000	5000	_	A/lm	
Gain <sup>E</sup>	ain <sup>E</sup>				$9.5 \times 10^{6}$	_	_	
Anode Dark Current <sup>F</sup> (After 30 min Storage in Darkness)				_	20	100	nA	
Time	Anoc	de Pulse	Rise Time G	_	— 2.2 —		ns	
_	Elec	tron Tra	ansit Time <sup>H</sup>		22		ns	
Response	Trans	it Time S	pread (T.T.S.) <sup>I</sup>	_	1.2	_	ns	
Anode Cur	rent	Light H	lysteresis	_	0.5	_	%	
Stability J Voltage Hysteresis				_	1.0	_	%	

#### **NOTES**

- A: Averaged over any interval of 30 seconds maximum.
- B: The light source is a tungsten filament lamp operated at a distribution temperature of 2856 K. Supply voltage is 100 V between the cathode and all other electrodes connected together as anode.
- C:Red/White ratio is the quotient of the cathode current measured using a red filter (Toshiba R-68) interposed between the light source and the tube by the cathode current measured with the filter removed under the same conditions as Note B.
- D:The value is cathode output current when a blue filter (Corning CS 5-58 polished to 1/2 stock thickness) is interposed between the light source and the tube under the same condition as Note B.
- E: Measured with the same light source as Note B and with the voltage distribution ratio shown in Table 1 below.

**Table 1:Voltage Distribution Ratio** 

Electrodes	ŀ	<	Dy	1 D	y2	Dy3	D	y4	Dy	5 C	y6	Dy	/7	Dy	/8	Dy	у9		Р
Ratio		1		1	1	ı	1	,	1	1		1		1		1		1	

Supply Voltage: 1000 V, K: Cathode, Dy: Dynode, P: Anode

- F: Measured with the same supply voltage and voltage distribution ratio as Note E after removal of light.
- G:The rise time is the time for the output pulse to rise from 10 % to 90 % of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- H:The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitube. In measurement, the whole photocathode is illuminated.
- I: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times
- J: Hysteresis is temporary instability in anode current after light and voltage are applied.

$$Hysteresis = \frac{I_{max.} - I_{min.}}{I_{i}} \times 100 (\%)$$

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#### (1)Light Hysteresis

The tube is operated at 750 V with an anode current of 1  $\mu A$  for 5 minutes. The light is then removed from the tube for a minute. The tube is then re-illuminated by the previous light level for a minute to measure the variation.

#### (2)Voltage Hysteresis

The tube is operated at 300 V with an anode current of 0.1  $\mu$ A for 5 minutes. The light is then removed from the tube and the supply voltage is quickly increased to 800 V. After a minute, the supply voltage is then reduced to the previous value and the tube is re-illuminated for a minute to measure the variation.



Figure 4: Typical Temperature Characteristics of Dark Current (at 1000 V, after 30 min storage in darkness)

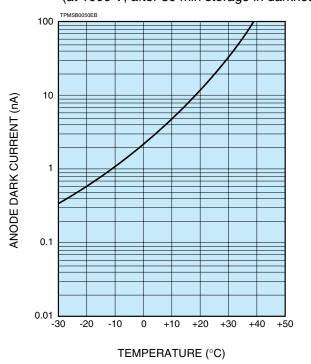


Figure 5: Anode Luminous Sensitivity and Gain Characteristics

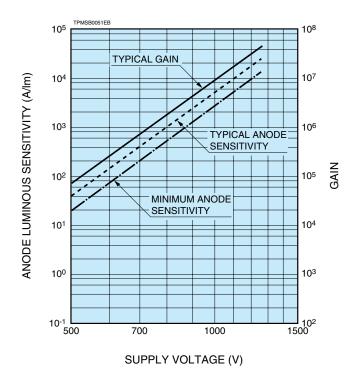


Figure 6: Typical Time Response

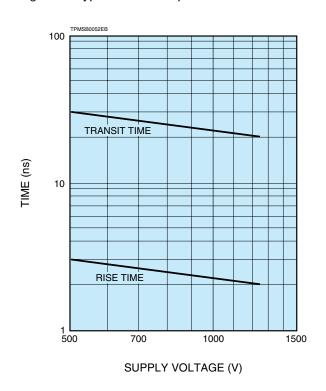
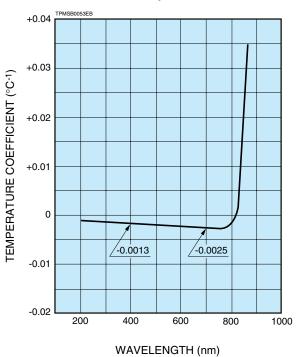


Figure 7: Typical Temperature Coefficient of Anode Sensitivity



## PHOTOMULTIPLIER TUBE R13096

Figure 8: Dimensional Outline and Basing Diagram (Unit: mm)

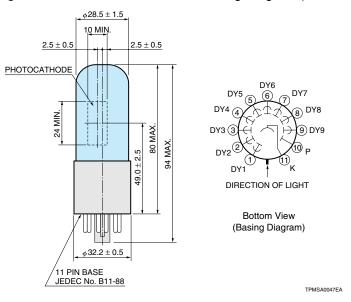
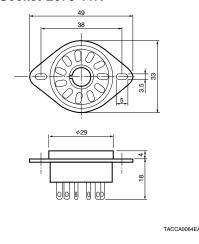
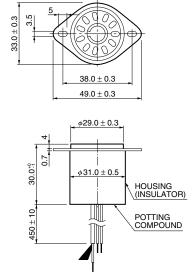


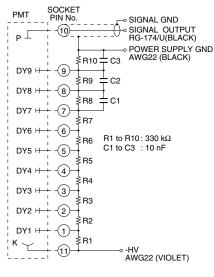
Figure 9: Accessories (Unit: mm) Sold Separately

#### Socket E678-11A



### D Type Socket Assembly E717-63





TACCANNOEH

\* Hamamatsu also provides C4900 series compact high voltage power supplies and C6270 series DP type socket assemblies which incorporate a DC to DC converter type high voltage power supply.

### Warning-Personal Safety Hazards

Electrical Shock-Operating voltages applied to this device present a shock hazard.

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